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Review

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Efficient and stable perovskite light-emitting diodes

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Abstract: Perovskite light-emitting diodes (PeLEDs) have shown outstanding potential in next-generation lighting and display owing to the advantages of broad spectral tunability, excellent color purity, high efficiencies, and low processing cost. Device efficiency and stability are crucial indicators to evaluate whether a PeLED can meet commercial application requirements. In this review, we first discuss strategies for achieving high external quantum efficiencies (EQEs), including controlling charge injection and balance, enhancing radiative recombination, and improving light outcoupling efficiency. Next, we review recent advances in operational stability of PeLEDs and emphasize the mechanisms of degradation in PeLEDs, including ion migration, structural transformations, chemical interactions, and thermal degradation. Through detailed analysis and discussion, this review aims to facilitate progress and innovation in highly efficient and stable PeLEDs, which have significant promise for display and solid-state lighting technologies, as well as other emerging applications.

Key words: Perovskite; Light-emitting diodes; External quantum efficiency; Stability

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1 Introduction

In the pursuit of innovative light sources to revolutionize display and lighting technologies, perovskite light-emitting diodes (PeLEDs) have emerged as a promising candidate (Tan et al., 2014; Cho et al., 2015). They possess advantages of broad spectral tunability, excellent color purity, high luminescence quantum yields (PLQYs), and low cost. Since the first report of room-temperature electroluminescence (EL) in halide perovskite (Tan et al., 2014), the field has witnessed a remarkable growth.

Through improvements in emissive perovskites and device structures, the external quantum efficiencies (EQEs) of PeLEDs with emission wavelengths varying from green to near-infrared (NIR) have exceeded 30% (Feng et al., 2024; Li M et al., 2024; Sun et al., 2024). And the EQEs of blue PeLEDs have surpassed 20% (Gao et al., 2024). Despite these encouraging improvements in efficiency for PeLEDs, operational stability remains a significant challenge. A recent breakthrough showcased efficient NIR PeLEDs with a remarkable operational lifetime of 32,675 h at a current density of 3.2 mA cm^{-2} (Guo et al., 2022). However, visible PeLEDs still suffer from poor stability, which restricts their application in commercial display technologies.

In this review, we consider paths for further development in efficiency and stability for PeLEDs. First, we focus on strategies to create highly efficient PeLEDs, including controlling charge injection and balance, enhancing radiative recombination, and improving light outcoupling. Subsequently, we conclude the best-performing devices in terms of stability, and discuss degradation mechanisms in PeLEDs. By analyzing the efficiency and stability challenges faced by PeLEDs, we expect that further insights could be gained for improved device fabrication, facilitating commercial applications.

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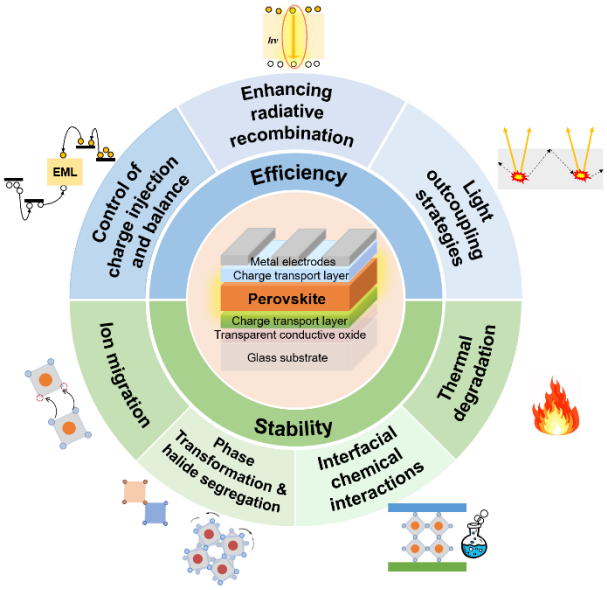

Fig. 1 Strategies for high efficiency and factors of instability in PeLEDs

2 Creating highly efficient PeLEDs

Typically, PeLEDs devices feature a sandwich-like structure, where the central perovskite emissive layer (EML) is flanked by the electron-transport layer (ETL) and the hole transport layer (HTL). Similar to the device architectures of OLEDs, the structures of PeLEDs can be classified into regular ("p-i-n") or inverted ("n-i-p") types (Guo et al., 2022; Zhao B et al., 2020). The most important metric for the efficiency of PeLEDs is the external quantum efficiency (EQE), which is the ratio between the number of emitted photons and the injected carriers per unit time (Cao et al., 2018; Xu et al., 2019).

The EQE of PeLEDs can be determined by:

$$\begin{aligned} \mathrm{EQE} &= \mathrm{IQE} \times f_{\mathrm{outcoupling}} \\ &= f_{\mathrm{balance}} \times f_{\mathrm{e\text{-}h}} \times \eta_{\mathrm{rad}} \times f_{\mathrm{outcoupling}} \end{aligned} \tag{1}$$

where IQE is the internal quantum efficiency, f_{balance} is the factor of charge injection balance, $f_{\mathrm{e\text{-}h}}$ is the probability of producing a correlated electron–hole pair generated from each pair of injected carriers, η_{rad} is the radiative recombination efficiency of each electron–hole pair, and $f_{\mathrm{outcoupling}}$ is the optical outcoupling efficiency (Stranks et al., 2019; Zhao et al., 2023).

According to this formula, building PeLEDs with higher EQEs requires enhancing both IQE and $f_{\mathrm{outcoupling}}$. IQE is determined by f_{balance}, $f_{\mathrm{e\text{-}h}}$, and η_{rad}. The charge balance (f_{balance}) can be improved by optimizing energy level alignment (Zhao and Tan, 2020; Zhao B et al., 2020) and charge transport properties (Zhao et al., 2018). Main strategies for improving $f_{e\text{-}h}$ include forming charge-confinement structures (Wang et al., 2016; Yuan et al., 2016), and reducing the dielectric constants to enhance Coulomb interactions (Jiang et al., 2021; Stranks et al., 2019). For perovskite emitters, η_{rad} is determined by $\eta_{\mathrm{rad}} = k_2N^2/(k_1N+k_2N^2+k_3N^3)$, where k_1 is the trap-assisted recombination rate, k_2 is the rate of band-to-band radiative recombination, k_3 is the Auger recombination constant, and N is the carrier concentration (Stranks et al., 2019; Zhao et al., 2023). Enhancing $f_{\mathrm{outcoupling}}$ requires suppressing the light losses from the substrate and waveguide modes, so the light management strategies are essential for maximizing photon extraction (Cho et al., 2020; Zhao et al., 2023).

2.1 Control of charge injection and balance

When applying a forward bias between the electrodes of PeLEDs, the electrons and holes migrate through the charge-transport layer (CTL) to the EML, where they recombine to emit light (Tan et al., 2014). Energy level barrier and interface mismatches between electrodes and EMLs can hamper charge injection. Therefore, to achieve efficient charge injection, it is crucial to ensure proper energy level alignment so as to minimize the injection barrier. Also, ETL with deep highest occupied molecular orbitals (HOMO) and HTL with shallow lowest unoccupied molecular orbitals (LUMO) can block electrons and holes, respectively, confining recombination to the perovskite layer (Fig. 2a) (Li Y et al., 2024; Tan et al., 2014).

To function efficiently, PeLEDs require not only effective charge carrier injection but also a balanced distribution of electrons and holes. It is essential to minimize charge imbalance losses, which can occur if one carrier type is in excess (Fig. 2b) (Chen Z et al., 2021; Zou et al., 2019).

2.1.1 Optimizing energy level alignment

Due to the significant energy level barrier between the electrode and the perovskite layer, selecting appropriate charge transport layers to optimize energy level alignment is essential for efficient charge carrier

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injection. The commonly used CTLs in PeLEDs are summarized in Fig. 2c. To enhance charge injection efficiency, designing a well-constructed energy level cascade is an effective strategy (Yu et al., 2022; Zou et al., 2020). By successively depositing multiple layers of HTLs—poly(3,4-ethylenedioxythiophene)-poly (styrenesulfonate) (PEDOT:PSS), poly(N,N′-bis-4-butylphenyl-N,N′-bisphenyl (Poly-TPD), and poly(N-vinylcarbazole) (PVK)—on the ITO substrate, an energy cascade can be created to optimize hole injection. The HOMO levels progressively deepened from -5.0 eV (PEDOT:PSS) to -5.8 eV (PVK), aligning closely with the VBM of $CsPbBr_3$ (-5.8 eV), and thus reducing the hole injection barrier. This alignment led to improved device efficiency and reduced EQE roll-off (Zou et al., 2020).

Introducing mixed organic CTLs is also an effective approach to adjust energy band structures. By incorporating the electron-accepting molecule 1,3,5-tris (bromomethyl) benzene (TBB) into HTL (Poly-TPD), energy level alignment can be improved. Adjusting the concentration of TBB deepens the LUMO level of the mixed HTL from -5.10 eV to -5.42 eV, better aligning it with the VBM of the green EML (Wang H et al., 2020).

2.1.2 Balancing the charge transport

When excess electron (or hole) injection occurs, this imbalance can be corrected by either impeding the electron (or hole) transport, or accelerating the transport of holes (or electrons) (Fakharuddin et al., 2019). For example, more electrons can be injected from the ETL than holes from the HTL, leading to an uneven spatiotemporal distribution of holes and electrons across the device structure (Wang et al., 2019). Balancing the charge transport is important for maintaining charge injection balance.

Introducing an insulation layer on one side of PeLEDs is a typical strategy for balancing charge transport, which improves the carrier utilization and leads to efficiency improvement. It was reported that insulating polymethyl methacrylate (PMMA) can be introduced to separate the ETL and the cathode. The insulating PMMA effectively impeded the excess electron flow, balancing the electron and hole injection, and moving the carrier recombination region towards the central region of the EML (Lin et al., 2018).

While the introduction of an insulating layer can reduce excessive electron injection, it may also result in electron accumulation and increased Joule heating. Regulating the carrier polarity and concentration within the perovskite layer is also an effective way to optimize the device structure, ensuring efficient carrier injection and balance. By introducing a phosphonic acid molecular dopant with strong electron-withdrawing properties, a transition from n-type to p-type conductivity in the perovskite semiconductor can be achieved (Fig. 2d), significantly enhancing hole transport and shifting the carrier recombination region. PeLEDs based on the p-type perovskite achieved ultra-high luminance ($>1.1\times10^6$ cd m^{-2}) (Fig. 2e), EQE (28.4%), and a record-high energy conversion efficiency for visible PeLEDs (23.1%) (Xiong et al., 2024), demonstrating the importance of electrical doping in perovskites for improving charge transport in PeLEDs.

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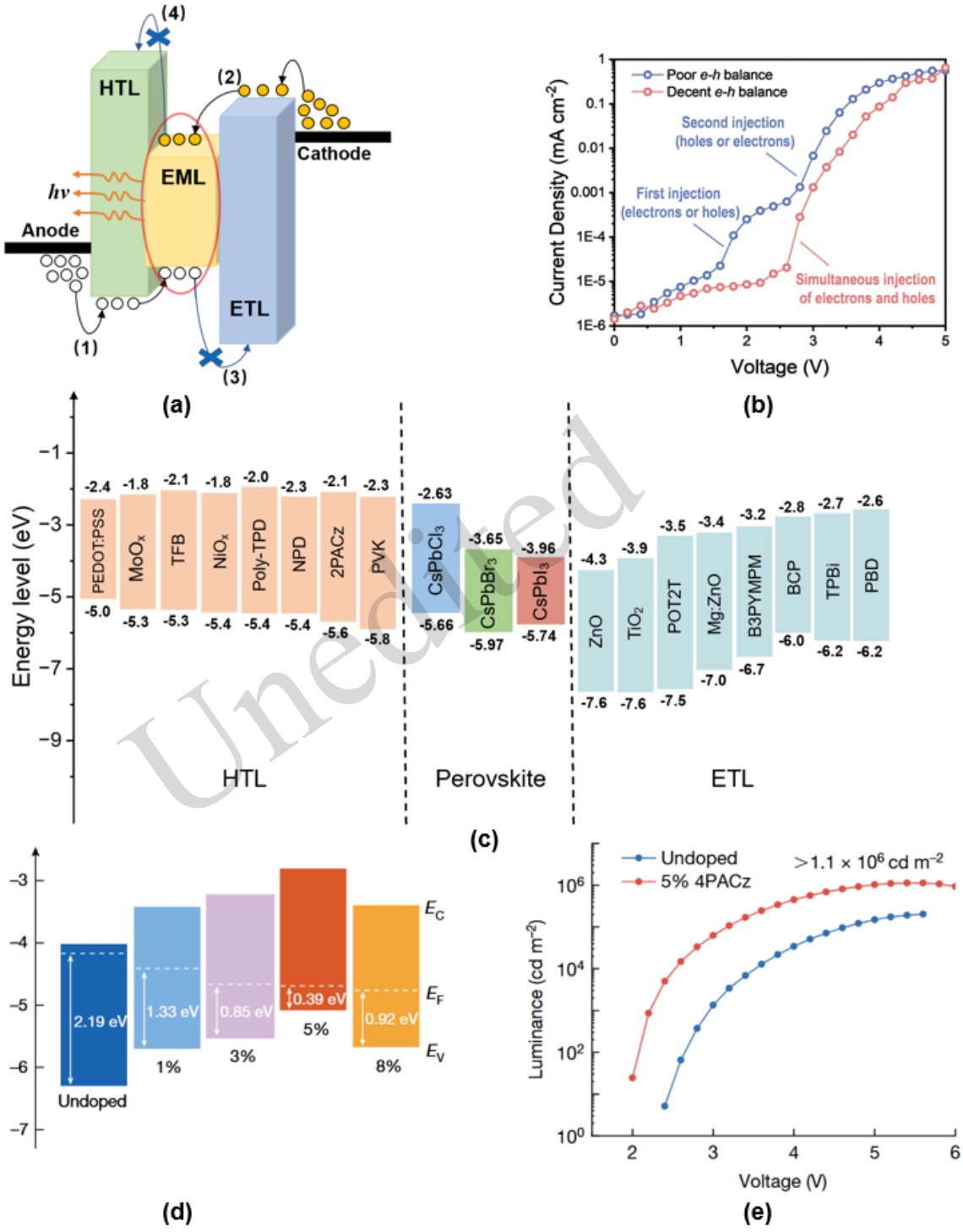

Fig. 2 (a) Diagram of a PeLED with a "regular" structure. The numbers reveal the functional contributions of HTLs and ETLs: 1) hole injection; 2) electron injection; 3) hole blocking; 4) electron blocking. (b) The J–V curves for poor and decent electron-hole balances in PeLEDs. (c) Energy levels of commonly used ETLs and HTLs for $CsPbCl_3$, $CsPbBr_3$, and $CsPbI_3$ perovskite layers. (d) Schematic of the structure architecture of PeLEDs with insulating PMMA between the ETL and cathode. (e) Energy levels of the perovskite samples with different doping concentrations. Fig. 2a and 2c are reprinted from Li Y et al. (2024). Fig. 2b is reprinted from Chen Z et al. (2021). Fig. 2d and 2e are reprinted from Xiong et al. (2024).

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2.2 Enhancing radiative recombination

The charge carrier recombination kinetics dependency on carrier density can be described by:

$$-\frac{\mathrm{d}N(t)}{t} = k_1 N + k_2 N^2 + k_3 N^3 \qquad (2)$$

where k_1 is the trap-assisted recombination rate, k_2 is the band-to-band radiative recombination rate, k_3 is the Auger recombination constant, and N is the carrier concentration (Fig. 3a) (Luo et al., 2019; Quan et al., 2017; Stranks et al., 2019). Due to the relatively small exciton binding energy (~10 meV), excitons in three-dimensional (3D) perovskites can easily dissociate into free carriers, which can be captured by defect centers at low carrier densities; this leads to enhanced trap-assisted recombination (Stranks et al., 2019). Simulation results show that low k_2 is a significant factor limiting the carrier recombination of 3D perovskites (Fig. 3b) (Cao et al., 2018). A recent study demonstrated that incorporating dual additives into $FAPbI_3$ perovskite leads to higher exciton binding energy, which effectively accelerates radiative recombination and thus achieves a remarkable peak EQE of 32% in NIR PeLEDs (Fig. 3d) (Li M et al., 2024).

Trap-assisted recombination and Auger recombination are also significant factors limiting efficiency improvement in PeLEDs. At moderate to low carrier densities, trap-assisted recombination is the main cause of non-radiative losses. It dominates at carrier density (N) < 5×10^{16} cm^{-3}, making trap passivation crucial for improving PeLED performance (Fig. 3c) (Fakharuddin et al., 2022; Richter et al., 2016). At higher carrier densities (N > 10^{18} cm^{-3}), enhancing the Auger recombination causes efficiency losses (Richter et al., 2016; Xing et al., 2017).

2.2.1 Defect passivation

To limit trap-assist recombination, it is critical to inhibit the formation of defects in perovskite crystal, including interstitial defects, vacancy defects, and anti-site substitution defects (Fig. 3e) (Ball and Petrozza, 2016; Liu X et al., 2021). This is often achieved by the incorporation of small-molecule (Ban et al., 2018) and polymeric (Zhao et al., 2018) passivators through direct addition to perovskite precursors, or post treatments on crystallized perovskites (Nenon et al., 2018; Xu et al., 2019). Numerous agents or ligands have proven effective at decreasing the defect density of perovskites, such as Lewis acid/base moieties, organic components with positive or negative charges, and alkali metal ions (Lee et al., 2019; Liu X et al., 2021; Shen et al., 2023).

The deep-lying traps leading to efficiency loss are thought to mainly stem from undercoordinated lead, including Pb^{2+} and Pb^0 (Chen et al., 2019). Lewis bases functional groups, including phosphine oxide (P=O), carboxyl (-COOH) and carbonyl (C=O), are widely used to passivate Pb^{2+} by donating lone electron pairs (Lee et al., 2018; Quan et al., 2020; Ren et al., 2021; Shen et al., 2023). Meanwhile, certain polymers and small molecules with functional groups capable of furnishing lone electron pairs have been used to passivate defects in perovskites, in order to enhance the efficiency and operational stability of PeLEDs. Moreover, alkali metal ions (Li^+, K^+ and Rb^+) can be utilized to passivate defects, thereby optimizing device performance (Guo Z et al., 2021; Li et al., 2020). A notable example involves the treatment of mixed halide perovskite nanocrystals with the ligands ethylenediaminetetraacetic acid (EDTA) and reduced l-glutathione, which bind strongly to lead atoms on the crystal surface to suppress halide segregation. This approach has yielded highly efficient and color-stable red PeLEDs, which achieved a EQE of 20.3% (Hassan et al., 2021).

Additionally, the effectiveness of multiple-passivator strategies has been reported. For example, the ionic liquid [BMIm]OTf was found to act as a crystallization modulator via heterogeneous nucleation, and a multi-site passivator—$[BMIm]^+$ —binds to uncoordinated Br^- while OTf^- coordinates with Pb^{2+} defects (Luo et al., 2022). This dual passivation suppresses nonradiative recombination while optimizing the morphology of the perovskite. Furthermore, the role of alkali metal ions was shown to extend beyond simple defect passivation. In quasi-2D perovskites, the relatively large radius of K^+ was reported to result in weaker Coulomb interactions with the $[PbBr_6]^{4-}$ frames, restricting the formation of high-n phases and promoting the homogeneous distribution of low-n phases, achieving a peak EQE of ~18.2% (Guo Z et al., 2021).

2.2.2 Interfacial modification

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Interfacial non-radiative recombination loss plays an equally important (if not more important) role compared to bulk regions in terms of performance improvement of PeLEDs. The perovskite layer is typically deposited on CTL by spin-coating, and differences in the interfacial properties between the two layers can affect the crystallization and morphology of the perovskite layer, thereby leading to current leakage and non-radiative recombination losses.

These shortcomings can be improved through various interface modification methods, including introducing perovskite epitaxial growth templates (Zhang et al., 2022), modifying hydrophobic surfaces (Si et al., 2017; Xiao et al., 2017; Zhao B et al., 2020), and employing self-assembled monolayers (SAMs) (Xiong et al., 2023; Zhou et al., 2023). As reported, ultrathin polar interfaces like lithium fluoride (LiF) can facilitate the formation of high-quality perovskite films on hydrophobic polymeric CTL (Fig. 3f), which acts as an effective template to form perovskite grains with fewer voids; this can remarkably improve the quality of the perovskite layers (Zhao B et al., 2020).

2.2.3 Dimensionality regulation

In conventional 3D PeLEDs, due to the relatively low exciton binding energy, excitons are prone to being captured by defects, which leads to non-radiative recombination. In contrast, perovskites with low-dimensional and nanocrystalline structures exhibit the quantum confinement effect, which increases the exciton binding energy (Liu X et al., 2021; Quan et al., 2017). To this end, research into mixed-dimensional perovskite systems featuring multiple quantum well (MQW) structures has been initiated. Through the energy funneling mechanism, carriers are confined within the lower-bandgap perovskite regions, thus improving the local carrier density and enhancing radiative recombination (Fig. 3g) (Cheng et al., 2020; Wang et al., 2016; Yuan et al., 2016).

However, in low-dimensional perovskite systems, the carrier density at the recombination center is significantly higher than in 3D perovskites, leading to more severe Auger recombination and causing PLQY to decline rapidly at a relatively low carrier density threshold. This causes the EQE roll-off to be more pronounced (Fig. 3h) (Jiang et al., 2021). A recent study employed a double-edge contacted epitaxy (de-epitaxy) heterostructure combining quantum dots (QDs) and quasi-2D $CsPbI_3$ films, which preserves the excellent charge transport properties of the quasi-2D perovskite while enhancing the PLQY of the QDs (Fig. 3i). This approach also improved the stability of the perovskite crystal phase, achieving a peak EQE of 24.6% and high stability in red PeLEDs (Wei et al., 2025).

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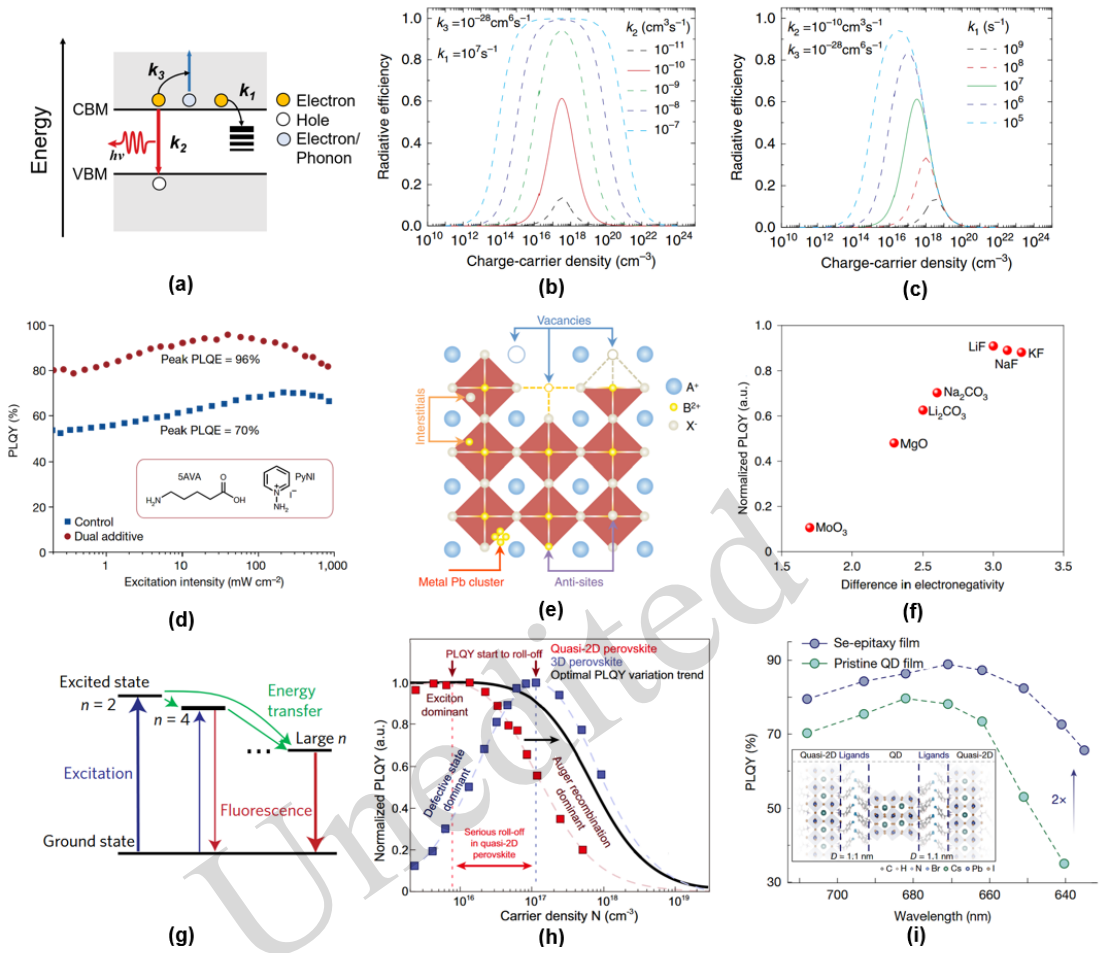

Fig. 3 (a) Recombination pathways in 3D perovskite. k_1 is the trap-assisted recombination rate, k_2 is the band-to-band radiative recombination rate, k_3 is the Auger recombination constant. (b, c) Related radiative efficiency-charge carrier density characteristics with (b) varying band-to-band radiative recombination coefficients k_2, (c) varying trap-assisted recombination coefficients k_1. (d) Excitation-intensity-dependent PLQYs of control and dual-additive perovskites. (e) Point defects of perovskites including interstitial defects, vacancy defects, anti-site substitution defects, and metal Pb clusters. (f) Normalized PLQYs of perovskite layers deposited on a range of interfacial materials with differences in electronegativity of the chemical bonds. (g) Schematic of cascade energy transfer in MQWs. (h) Experimental PLQYs of quasi-2D perovskite and 3D perovskite films as a function of carrier density. (i) Maximum PLQYs of different-sized pristine QD films and $CsPbI_3$ QD se-epitaxy films. Fig. 3a is reprinted from Quan et al. (2017). Fig. 3b and 3c are reprinted from Xing et al. (2017). Fig. 3d is reprinted from Li M et al. (2024). Fig. 3e is reprinted from Liu X et al. (2021). Fig. 3f is reprinted from Zhao B et al. (2020). Fig. 3g is reprinted from Wang et al. (2016). Fig. 3h is reprinted from Jiang et al. (2021). Fig. 3i is reprinted from Wei et al. (2025).

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2.3 Light outcoupling strategies

The IQEs of top-performing PeLEDs are currently nearing unity, while approximately 80% of generated photons remain confined within the device due to limited light outcoupling yields (Lin et al., 2018; Wang et al., 2016; Zhao et al., 2018). This limited outcoupling efficiency results from two primary factors: (1) waveguide modes induced by the higher refractive indices of perovskites (~2.5) compared with commonly used charge transport materials and transparent electrodes (~1.7-1.8) (Zhao et al., 2018). (2) Total light internal reflection across a wide range of angles due to the refractive index mismatch between the device substrate and air (Cho et al., 2020; Zhao et al., 2023).

To improve EQEs of PeLEDs, extracting trapped photons from the device is essential. Strategies to enhance light outcoupling in PeLEDs can be broadly categorized into two approaches: modulation of intrinsic optical properties, and optimization of external optical structures (Zhao et al., 2023).

2.3.1 Modulation of intrinsic optical properties

Techniques for modulation of intrinsic optical properties include the reduction of refractive index (n) (Zhao et al., 2018), orientation of transition dipole moments (TDMs) (Cho and Greenham, 2021; Cui et al., 2021; Fieramosca et al., 2018; Proppe et al., 2020; Shen et al., 2019; Zou and Lin, 2020), and photon recycling (Cho et al., 2020).

According to the ray optics limit of $1/2n^2$, the reduction of n can increase $f_{\text{outcoupling}}$ for planar devices (Richter et al., 2016). For typical 3D perovskites (n≈2.5), the outcoupling efficiency is around 10%. To reduce n, creating perovskite-polymer bulk heterostructures (PPBH) by introducing polymers into the perovskite emissive layers is effective. This approach results in n~1.9 and improves the $f_{\text{outcoupling}}$ to ~21% (Fig. 4a) in near-infrared PeLEDs (Zhao et al., 2018).

The orientation of TDMs significantly influences photon extraction processes, with horizontally oriented TDMs enhancing the light extraction. The ratio of horizontal TDMs can be adjusted by engineering the perovskite nanostructures (Cui et al., 2021; Fieramosca et al., 2018; Proppe et al., 2020; Shen et al., 2019). For PeLEDs based on nanoplatelets, the ratio of horizontal TDMs was reported as ~84%, and the $f_{\text{outcoupling}}$ was 31% (Cui et al., 2021). The orientations of TDMs also can be tuned by solution-processed polycrystalline perovskite films (Fig. 4b) (Zou and Lin, 2020). Meanwhile, a slightly preferred orientation (horizontal dipole ratio of 0.41) can lead to a $f_{\text{outcoupling}}$ value of over 20%, and a maximum EQE of 36% (Zou and Lin, 2020).

Photon recycling enhances the light outcoupling by randomizing the directions of trapped photons through the reabsorption of photons and re-emitting processes (Bowman et al., 2020; Cho et al., 2020; Richter et al., 2016; Stranks et al., 2019). A typical approach for improving the photon recycling contribution is increasing the thickness of perovskite film (Fig. 4c) (Cho et al., 2020). Notably, using a relatively thick (~ 2.2 μm) emissive layer led to a high EQE exceeding 15%, while the calculated $f_{\text{outcoupling}}$ value based on the conventional model was only around 4.3% (Chen J et al., 2021).

The theoretical EQE of a PeLED with photon recycling is given by:

$$\mathrm{EQE}_{\mathrm{PR}} = f_{\text{balance}} \times f_{\text{out, direct}} \Big/ \left[f_{\text{out, direct}} + A_{\text{para}} + \frac{1-\eta_{\text{rad}}}{\eta_{\text{rad}}} \right] \quad (3)$$

where f_{balance} is the charge balance factor, $f_{\text{out, direct}}$ is the direct light out-coupling efficiency, and A_{para} is the parasitic absorption external to the perovskite layer (Cho et al., 2020).

2.3.2 Management of external optical structures

External optical structures, including lens (Kim et al., 2021; Shen et al., 2019) and microcavities (Miao et al., 2020), are useful for enhancing light outcoupling. Optimizing reflective index matching (Chen and Nurmikko, 2017; Lova et al., 2018) and employing plasmonic effects (Zhang et al., 2017) have also been demonstrated to improve $f_{\text{outcoupling}}$ for PeLEDs. Light extraction nanostructures, such as light-outcoupling hemispherical lens have been employed to reduce waveguide and substrate modes, improving maximum EQEs of PeLEDs from 20.3% to 28.2% (Shen et al., 2019). Optical microcavities have also been employed to enhance light extraction and improve the emission properties of top-emitting PeLEDs, resulting in an increase of $f_{\text{outcoupling}}$ from ~20% to ~30%; ultimately, peak EQEs of up to 20.2% were achieved (Miao et al., 2020).

Moreover, building rough or patterned surfaces is an effective strategy to overcome the extraction limit of PeLEDs. By doping with 5-aminovalericacid, the submicrometre structures of perovskite can efficiently improve light extraction and result in a peak EQE of 20.7%, through randomization of the paths of emitted photons (Fig. 4d) (Cao et al., 2018). Additionally, it was reported that a textured perovskite layer surface boosted the $f_{\text{outcoupling}}$ value significantly, from 11.7% to 26.5%, and the peak EQE was improved from ~10% to 20.5% (Chen et al., 2022).

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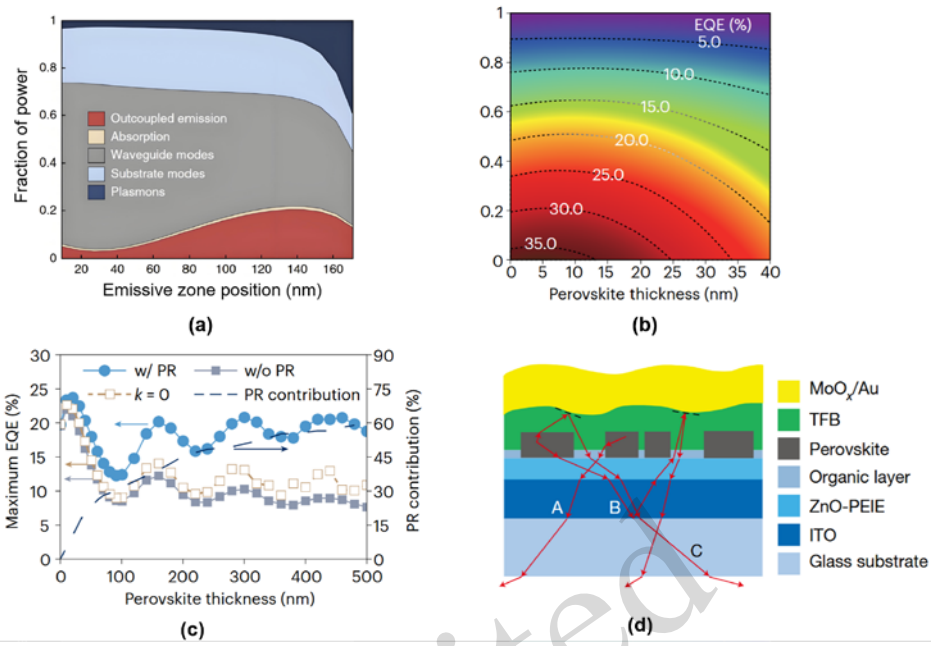

Fig. 4 (a) Simulated fraction of power in the LED architecture as a function of emissive zone position in the PPBH emissive layer. (b) Simulated EQE (color scale) as a function of $CsPbBr_3$ perovskite layer thickness and vertical dipole fraction (Θ). (c) Simulated maximum EQE and photon recycling contribution as functions of perovskite layer thickness for a PeLED device. (d) Diagram of light extracted by the submicrometre structure in PeLEDs. Fig. 4a is reprinted from Zhao et al. (2018). Fig. 4b is reprinted from Cui et al. (2021) and Zhao et al. (2023). Fig. 4c is reprinted from Cho et al. (2020) and Zhao et al. (2023). Fig. 4d is reprinted from Cao et al. (2018).

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3 Achieving highly stable PeLEDs

Currently, PeLEDs exhibit excellent EQEs and brightness that are comparable to (even superior to) those of OLEDs. However, the operational lifetimes (T_{50}, or the time for the emission intensity to decrease to 50% of the initial value) of PeLEDs is still insufficient for their commercialization (>10,000 hours required under required operational radiance). Here, we review the latest advances in operational stability of PeLEDs, represented by NIR, green and blue wavelength examples, and also analyze the degradation mechanisms of PeLEDs (which are primarily related to the ionic characteristics of the perovskite lattice). The aim is to provide a reference for research into ultra-long operational lifetime PeLEDs across the entire spectrum of commercial applications.

3.1 State-of-the-art devices

Here we discuss recent breakthroughs in long-operational-lifetime PeLEDs with various emission wavelengths (from blue to NIR). By comparing the T_{50} of PeLEDs with different colors under the same current density or irradiance, it can be found that NIR PeLEDs exhibit significantly higher operational stability than their visible counterparts (Table 1). Green, red, and blue PeLEDs have also seen encouraging progress (Dong et al., 2025; Kim et al., 2022; Kong et al., 2024), highlighting the potential for such PeLEDs in display technologies. To obtain ultra-long operational lifetimes which cannot be measured through long-term experiments, accelerated aging tests have been proposed to model the degradation of LEDs under different current densities, following this principle:

$$R_0^n \times T_{50} = \text{constant} \quad (4)$$

where R_0 is the initial radiance, and n is the acceleration factor.

NIR PeLEDs have demonstrated excellent stability on par with that of OLEDs, thus meeting the demands of commercial applications. For instance, ultra-stable operation of efficient $FAPbI_3$ PeLED (Fig. 5a) (peak EQE = 22.8%), with no degradation over 3,600 h at 5 mA cm^{-2}, has been demonstrated (Guo et al., 2022). T_{50} lifetimes of the PeLEDs, estimated by accelerated aging tests on 62 devices working under different current densities (Fig. 5b), were found to reach 32,675 h (3.7 years) at an initial radiance of 2.1

W sr^{-1} m^{-2} (which is equivalent to green OLEDs operating at 1,000 cd m^{-2}). Moreover, an ultra-long lifetime of ~2.4 ×10^6 h was projected at a lower radiance of 0.21 W sr^{-1} m^{-2}. This breakthrough is mainly attributed to the introduction of sulfobetaine-10 (SFB-10), a dipolar molecular stabilizer that can effectively interact with ions (FA^+, Pb^{2+}, I^-) at grain boundaries. Ion migration and formation of lead iodide were suppressed, contributing to the stabilization of the α-phase $FAPbI_3$ perovskite. These achievements alleviated the long-held concern that PeLEDs might be inherently unstable, and demonstrated their capability for commercial applications.

Green PeLEDs have shown the highest peak EQEs among PeLEDs of all colors (Bai et al., 2023; Liu et al., 2021). However, their typical T_{50} lifetimes were commonly several hundred hours on respective initial luminance (L_0) values (100~1000 cd m^{-2}), which is inferior to NIR PeLEDs operating under the same current density (Cheng et al., 2019; Han et al., 2021; Zhang et al., 2020). An advancement in the stability of green PeLEDs (Fig. 5c) resulted in a T_{50} of 520 h at an L_0 of 1,000 cd m^{-2}, and an extrapolated T_{50} lifetime of 31,808 h at an L_0 of 100 cd m^{-2} (Fig. 5d) (Kim et al., 2022). The key to this study was the nanocrystalline structure of perovskite surrounded by a benzyl phosphonic acid shell. BPA molecules formed covalent bonds with perovskite, which improved carrier confinement, passivated the undercoordinated lead atoms, and suppressed ion migration.

Br-I and Br-Cl mixing in perovskites is commonly used to adjust the bandgap for red and blue PeLEDs, respectively. However, red and blue PeLEDs are vulnerable to spectral shifting due to halide segregation (Vashishtha and Halpert, 2017; Yang et al., 2021). Sulfonamide, a dipolar molecular stabilizer, can effectively interact with the ionic species in the EMLs and suppress halide segregation; in this way, record-high T_{50} lifetimes of up to ~357 h at currents of ≥25 mA cm^{-2} were achieved in red PeLEDs (Ren et al., 2024). Besides, several methods to tune emission bandgaps of perovskites were proposed so as to avoid mixed-halide. For instance, through the introduction of A-site ions with a relatively small radius (such as Rb^+), there is contraction in the perovskite lattice, resulting in enhanced overlap between the lead and halide orbitals; this in turn leads to a blue shift in the emission wavelength. This method successfully reduced the Cl^- content in $CsPb(Br_xCl_{1-x})_3$ and further suppressed the formation of deep-level defects through Rb^+ compensation (Fig.5e, f) (Gao et al., 2024). In addition, the reduced-dimensional perovskites (RDPs) can also adjust bandgaps without having to use mixed halides for colour tuning (Lin et al., 2017; Yuan et al., 2016). A T_{50} of more than 7,600 min at an L_0 of 100 cd m^{-2} for pure-red (620-650 nm) PeLEDs has been achieved by incorporating double-end anchored ligand molecules with ammonium and methoxy groups, and MOPA into RDP pure-iodine perovskite; a T_{50} of 144 min at 0.45 mA cm^{-2} for deep-blue (459 nm) PeLEDs was achieved by a multivalent immobilization strategy involving introduction of a polyfluorinated oxygen-containing molecule into RDP (Fig. 5g) (Kong et al., 2024; Dong et al., 2025). Compared to NIR and green PeLEDs, achieving stable operation with red and blue PeLEDs and meeting the requirements of commercial applications (>10,000 h) is even more difficult. Future research is needed to solve these issues.

Looking ahead, in addition to pursuing ultra-long lifetimes at high brightness across the full color spectrum, the poor operational stability of lead-free PeLEDs should be addressed. To facilitate the development of PeLEDs into an environmentally friendly light-source technology, Ge-, Cu-, Eu-, Bi-, and Sb-based perovskite luminescent materials have been successfully developed as potential substitutes for lead in recent research. Some key factors contributing to poor stability in lead-free perovskite devices include uncontrollable self-doping and suboptimal film formation with alternative metals (Tang et al., 2024). Sn^{2+} has a propensity to be oxidized to Sn^{4+} through chemical reactions (Awais et al., 2021), and these deep-level defects lead to non-radiative recombination. A targeted strategy has been presented to eliminate Sn^{4+}-induced defects in $CsSnI_3$-based perovskites through moisture-triggered hydrolysis of tin tetrahalide, achieving improved stability with an operational lifetime of 82.6 h (Guan et al., 2024) (Fig. 5h, i). To further facilitate the development of PeLEDs into an environmentally friendly light-source technology, other strategies were developed to reduce the toxicity of lead in perovskites. These include Ge-, Cu-, Eu-, Bi-based perovskites and double perovskites (Min et al., 2023; Chung et al., 2012; Yang et al., 2021; Han et al., 2023). The high oxidation potential of Ge generated a stable native oxide passivation layer on the perovskite surface, thus enhancing the stability of the $CsSn_{0.5}Ge_{0.5}I_3$ perovskite (Chen et al., 2019). Addressing the issue of poor operational stability of lead-

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free PeLEDs is a critical goal in the field.

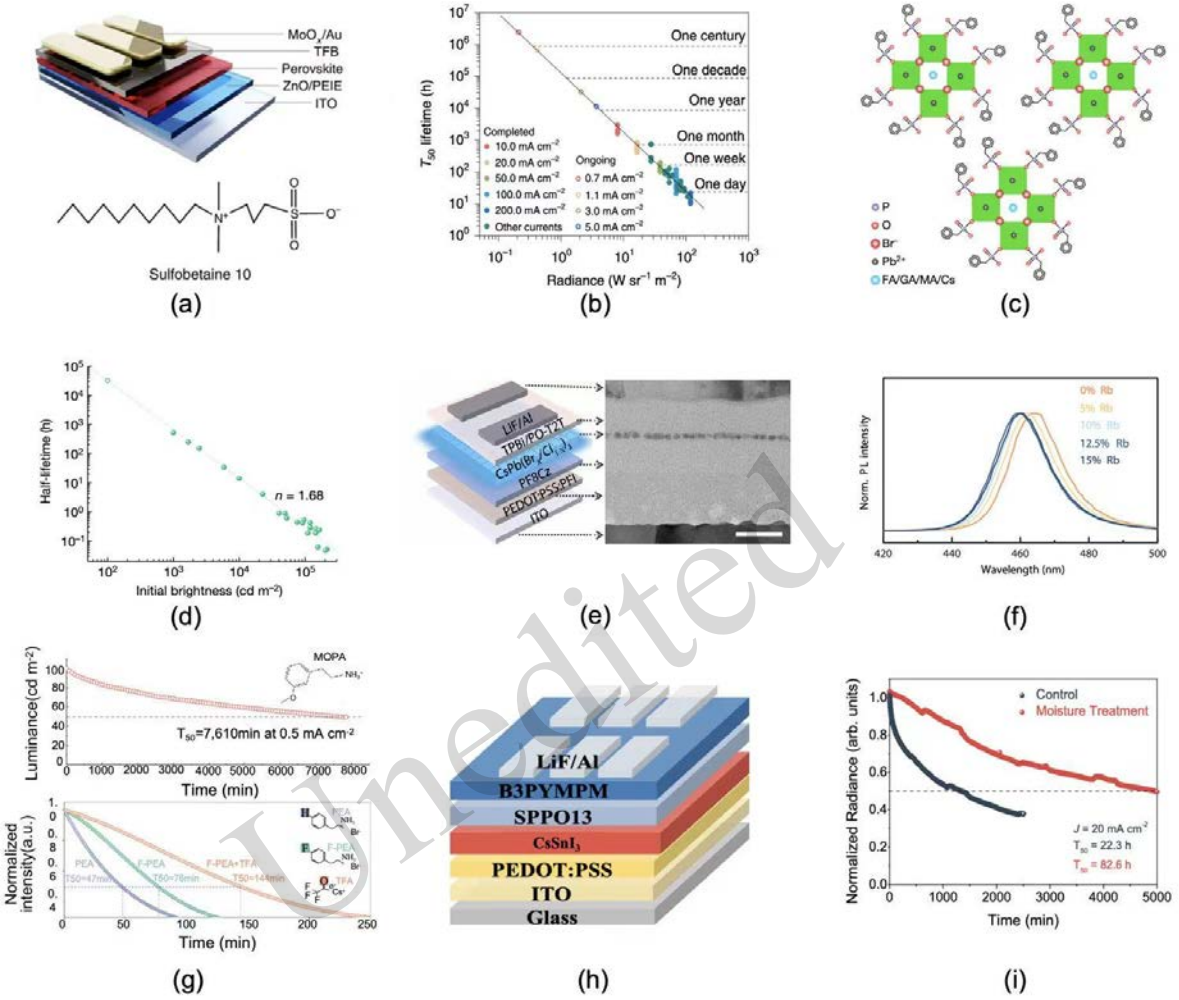

Fig. 5 (a) Device structure of NIR PeLEDs with ultra-long lifetimes, and the molecular structure of the SFB-10 stabilizer. (b) T_{50} lifetimes of PeLEDs stabilized with SFB-10; the solid line demonstrates the fitting of lifetime data from 62 devices based on accelerated aging tests. (c) Schematic illustration of in-situ core/shell structures with perovskite nanocrystals surrounded by BPA. (d) T_{50} lifetime results of in-situ core/shell PeLEDs. (e) Schematic diagram and cross-sectional TEM image of the blue PeLEDs. (f) The tunable PL peaks of $CsPb(Br_xCl_{1-x})_3$ nanocrystals with different incorporation levels of Rb^+. (g) Lifetimes of MOPA-treated PeLEDs at 0.5 mA cm^{-2}, where the inset displays the chemical structure of MOPA (top). Lifetimes of PEA, F-PEA, and TFA -treated PeLEDs at 0.45 mA cm^{-2}, where the inset displays the chemical structure of PEA, F-PEA, and TFA (bottom). (h) Device structure of the $CsSnI_3$-based PeLEDs. (i) Lifetimes of the $CsSnI_3$-based PeLEDs with and without moisture treatment. Fig. 5a and 5b are reprinted from Guo et al. (2022). Fig. 5c and 5d are reprinted from Kim et al. (2022). Fig. 5e is reprinted from Kong et al. (2024). Fig. 5e and 5f are reprinted from Gao et al. (2024) and Luo et al. (2020). Fig. 5g is reprinted from Kong et al. (2024) and Dong et al. (2025). Fig. 5h and 5i are reprinted from Guan et al. (2024).

3.2 Key mechanisms of degradation in PeLEDs

To overcome the instability of PeLEDs and meet the requirements for commercial applications, it is essential to explore the degradation mechanisms of PeLEDs. Ion migration is widely recognized as the primary cause of performance deterioration, while other contributing factors include phase transformation, halide segregation, interfacial chemical reactions, and thermal degradation.

3.2.1 Ion migration

Perovskites have a soft and deformable ionic structure with mixed electronic–ionic conduction properties, which facilitate ion motion (Li et al., 2022).

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The movement of ionic species in perovskites depends on the activation energy required for ions to move from one equilibrium position to another. Since the activation energy for ion migration in perovskites is typically low, external stimuli such as light, bias voltage, or heat can easily trigger directional migration of ions (Li et al., 2022; Zhao et al., 2024). In addition, concentration gradients can drive the diffusive migration of ionic species. The initial observation of ion motion in perovskites, which was characterized by an abnormal dielectric response at low frequency and hysteresis in the current-voltage curve, was made in perovskite solar cells (PSCs) (Snaith et al., 2014). In comparison with PSCs, PeLEDs are vulnerable to ion migration due to the excessive amount of organic halide salts in the precursor solution and the thinner emission layer (which typically measures tens of nanometers) (Dong et al., 2020).

Ion migration in PeLEDs can be classified into two categories according to their pathways: inside EMLs, and across the interfaces (Dong et al., 2020; Liu et al., 2021; Woo et al., 2021). Ion migration inside EMLs can lead to defect migration, annihilation and formation of Frenkel defects, adjustment of charge injection, and distortion of the crystal lattice (Fig. 6a). Additionally, ion migration across the interfaces can result in changes in CTL properties and chemical corrosion of electrodes (Fig. 6b) (Zhao et al., 2024). These detrimental effects result in displacements of EL spectra, EQE roll-off, and luminance quenching. Aside from the dipolar molecular stabilizer method mentioned above, several strategies have been proposed to suppress ion migration, including structural and dimensional modulation, molecular passivation (Cao et al., 2018), and heat management. For example, reduced-dimensional perovskites with monodispersed quantum wells were synthesized using tris(4-fluorophenyl)phosphine oxide (TFPPO), leading to a remarkable T_{50} lifetime of 115 minutes at L_0 of 7,200 cd m^{-2} (Ma et al., 2021).

3.2.2 Phase transformation and halide segregation

Phase transformations under undesirable operating conditions in perovskites involve abrupt crystal lattice rearrangement or changes in symmetry, which arise from the inherent structural instability of perovskites (due to their suboptimal tolerance and octahedral structure). The index typically used to evaluate the structural stability of perovskite crystals is the Goldschmidt tolerance factor, which can be calculated as (Travis et al., 2016):

$$t=\frac{r_A+r_X}{\sqrt{2}(r_B+r_X)} \tag{5}$$

where r_A, r_B, and r_X are the ionic radius of the A-site, B-site, and X-site ions, respectively. A value outside of the ideal range (which is between 0.8 and 1.0) is usually not conductive to forming a cubic perovskite structure (Jena et al., 2019). For instance, a photoactive α-phase $FAPbI_3$ perovskite is likely to degrade into a non-photoactive δ-phase at room temperature (Fig. 6c) (Fabini et al., 2016; Liu et al., 2023). Recently, low-concentration $MAPbBr_3$ (0.8 mol%) incorporation into $FAPbI_3$ has been shown to have a beneficial effect on stabilizing the α-phase (Yoo et al., 2021).

Halide ions with low activation energy dominate ion motion in MHPs. Halide segregation refers to the spatial compositional and structural heterogeneity that develops upon light illumination in MHPs. The formation of Br^- rich and Cl^- rich regions in $CsPbBr_xCl_{3-x}$ nanocrystals is due to the tendency of ion migration toward adjacent vacancy defects under bias, as well as the difference in affinity between Pb^{2+}, and Br^- and Cl^- ions, which separately facilitates the formation of $CsPbBr_3$ and $CsPbCl_3$ phases (Fig. 6d) (Luo et al., 2020). Some feasible solutions have been demonstrated to suppress halide segregation, including enhancing the barriers to halide ion migration using molecular stabilizers (Guo et al., 2022), reducing halide vacancies (Zheng et al., 2020), and vapor-assisted crystallization techniques to improve compositional homogeneity (Karlsson et al., 2021).

3.2.3 Interfacial chemical interactions

Interfacial electrochemical reactions occur under external bias, which is one of the main reasons for the poor stability of PeLEDs. The deprotonation of ammonium salt in organic-inorganic perovskites leads to interfacial degradation (Warby et al., 2020). For instance, $MAPbBr_3$ was reported to decompose into $PbBr_2$, MA^+, and Br^- under electrical stress (Prakasam et al., 2019). PEABr in quasi-2D PeLEDs also undergoes a similar decomposition reaction, and is accompanied by the transformation to 3D perovskites, which further results in EL quenching (Watanabe et al., 2019).

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Spontaneous interfacial chemical reactions between the EMLs and other layers may generate volatile byproducts which can penetrate the perovskite films, leading to phase transformation or film decomposition of the perovskite EMLs (Dong et al., 2020; Guerrero et al., 2016). Unlike ion migration and electrochemical reactions, these processes do not require external bias. The deprotonation reaction is more likely to occur with increased basicity of the metal oxide substrates and acidity of the ammonium cations (Fig. 6e), resulting in the formation of deep-level defects (Zeng et al., 2024). Typically, direct contact between ZnO ETL and $FAPbI_3$ perovskites leads to the formation of δ-$FAPbI_3$ and PbI_2, due to the deprotonation of the FA^+ cations (Yuan et al., 2019). In addition, protonation reactions may occur at the interfaces of HTLs and perovskites, as the sulfonic acid groups of PEDOT:PSS interact with halide perovskites, and further contribute to the instability of PeLEDs (Sun et al., 2021). Through surface treatment with dicarboxylic acids, which suppress deprotonation reactions between the ZnO ETL and the perovskite film, T_{50} of 682 h at 20 mA cm^{-2} for PeLEDs were achieved (Kuang et al., 2021).

In addition, metal ions in the electrodes and halide ions in the perovskite layer can infiltrate other functional layers through diffusion or migration. These ions then undergo chemical reactions with the substances in those layers, ultimately leading to device degradation. This process can be prevented through the insertion of barrier layers (Zhao et al., 2024).

3.2.4 Thermal degradation

Joule heating, which arises from the high resistance of perovskite layers and the poor thermal conductivity of glass substrates, can initiate thermal degradation of perovskite or charge-transport layers, leading to inferior operational stability (Kim et al., 2018; Zhao et al., 2019; Zhao et al., 2020). Perovskites containing MA tend to readily break down into MA vapor and PbI_2 when the temperature exceeds 85°C (Park et al., 2023). Moreover, significant heat accumulation occurs under high current densities. When operating at 300 mA cm^{-2}, the temperature of PeLEDs can quickly exceed 80°C within 100 seconds, which ultimately results in a dismal T_{50} value of 3 seconds (Fig. 6g) (Xu et al., 2020).

Thermal management strategies can significantly improve device stability, such as employing substrates with superior thermal conductivity to glass (e.g., SiO_2, sapphire) (Xu et al., 2020; Zou et al., 2020), modifying surfaces to enhance the thermal conductivity of the perovskite layers (Li H et al., 2024), and doping charge-transport layers (Zhao L et al., 2020). A fluoride post-synthesis treatment with DDAF on PeLEDs, based on $CsPbBr_3$ nanocrystals, enabled stable and temperature-independent PL of up to 373 K with 90% PLQY. In contrast, the PLQY of the control sample declined sharply to ~15% when the temperature was increased to 370 K (Fig. 6h) (Liu M et al., 2021).

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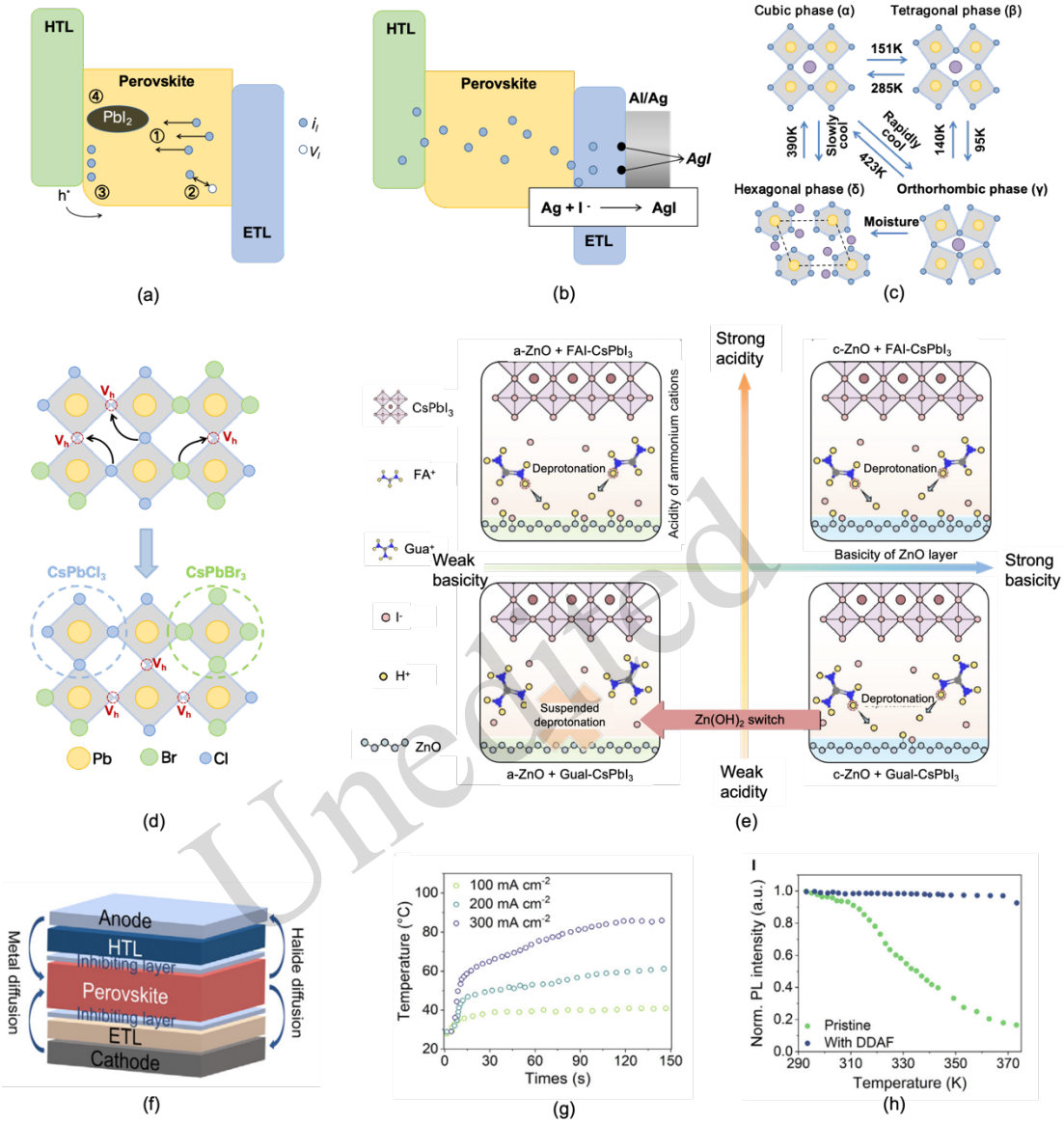

Fig. 6 (a) Schematic diagram of ion migration effects inside perovskite on operational stability, including 1) Defect migration, 2) annihilation and creation of Frenkel defects, 3) modification on charge injection, 4) distortion of the crystal lattice. (b) Ion migration across the interface results in electrode degradation. (c) Temperature dependence of phase transition of the crystal structure of the $FAPbI_3$ absorbers. (d) Schematic illustration of vacancy-assisted ion migration, resulting in Br-rich and Cl-rich regions. (e) Schematic of interfacial deprotonation reactions based on ZnO with increased basicity and ammonium cations with increased acidities. (f) The mechanisms of device degradation, including the diffusion of metallic species from electrodes and the migration of halide ions from perovskite degradation, which can be prevented by inserting barrier layers. (g) Surface temperature variations over time for a PeLED at 100, 200, and 300 mA cm^{-2}. (h) PL intensities of pristine and DDAF-treated perovskite films at increased temperatures. Fig. 6a and 6b are reprinted from Dong et al. (2020). Fig. 6c is reprinted from Liu et al. (2023). Fig. 6d is reprinted from Luo et al. (2020). Fig. 6e is reprinted from Zeng et al. (2024). Fig. 6f is reprinted from Zhao et al. (2024). Fig. 6g is reprinted from Xu et al. (2020). Fig. 6h is reprinted from Liu M et al. (2021).

4 Summary and outlook

Perovskites have emerged as promising materials for light-emitting diodes thanks to their remarkable attributes, including high color purity, high efficiency, high brightness, and tunable wavelengths. Recent breakthroughs in PeLEDs highlight their potential for applications in display and solid-state lighting. PeLEDs have demonstrated high

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efficiency across a range of emission wavelengths (from blue to NIR) – particularly green and red PeLEDs, which now achieve EQEs exceeding 30%. These achievements highlight the potential of PeLEDs as an alternative to OLEDs. Such advancements have largely been driven by improvements in the optical properties of the emissive perovskite layers, and the modification of device structures. We discussed the factors crucial for achieving near-unity IQEs, including enhancing effective charge injection and recombination, while suppressing non-radiative recombination losses. Additionally, employing controllable p- or n-type behaviors and charge concentration in perovskites, akin to III–V semiconductors, could further improve charge transport and enhance device performance (Xiong et al., 2024). Nevertheless, approximately 80% of the photons generated are retained within the device stack, and eventually dissipate their energy. As light outcoupling from PeLEDs improves, it may become feasible to achieve EQEs approaching 100%. Such an advancement could pave the way for low-cost ultra-high-performance light sources (Zhao et al., 2023).

Recent advances in the operational stability of PeLEDs with NIR and green emission wavelengths suggest that PeLEDs are transitioning from a laboratory curiosity to a commercially viable technology (Guo et al., 2022; Kim et al., 2022). To achieve long-term operational stability across the full color spectrum, future studies could concentrate on molecular stabilizers that mitigate the effects of ion migration and halide segregation, investigate suppression of chemical interactions at interfaces between perovskite grain boundaries and functional layers, and improve thermal management. Moreover, developing novel structure designs such as core-shell nanocrystals and heterostructures, along with effective interfacial layers and modifications, may further enhance the stability of PeLEDs. Furthermore, inorganic CTLs, which have played a key role in the exceptional stability of novel NIR PeLEDs, could be explored for further use in PeLEDs of different color ranges (Zhao et al., 2024).

Despite encouraging breakthroughs in PeLEDs, several issues must still be overcome. First off, high-performance standard blue PeLEDs (peak wavelengths ≤ 470 nm) are a rarity. Their EQEs are normally less than 15% with poor operational stability (Wang et al., 2020; Zhou et al., 2022), restricting application in wide-color-gamut displays. Future research should focus on understanding nucleation, crystallization, non-radiative losses, and the aging mechanisms of blue perovskite emitters in order to improve their efficiency and stability. Sn-based PeLEDs, which are not toxic, stand out as the most promising alternative to lead-based perovskites. However, the operational stability of Sn-based PeLEDs (which is currently limited to tens of hours) is severely lacking compared to their lead-based counterparts (Tang et al., 2024). The realization of high-performance lead-free perovskites therefore remains a critical research gap. Mitigating the toxicity of PeLEDs would pave the way for more successful commercial applications.

In addition, the long lifetimes under low brightness for PeLEDs, which are estimated by accelerated aging methods with data collected from short-term experiments, typically deviate from the true values. Methods that can obtain accurate long-term lifetime operation data need to be explored further, so as to offer an in-depth understanding of degradation mechanisms and promote improved operational stability of PeLEDs. Lastly, improving device performance under high-brightness operation remains a significant challenge for PeLEDs, which has thus far restricted their application in holographic imaging, lighting, and electrically pumped lasing. To increase the peak brightness and improve device stability under high current densities, key factors such as Auger recombination, charge transport, and Joule heating must be addressed.

Looking forward, we anticipate that significant challenges in PeLEDs, such as the limited performance of blue and lead-free devices, and the instability of visible PeLEDs, will be resolved. As such, the potential of this technology will be realized, and more stable and efficient PeLEDs may be developed.

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Table 1 Summary of the stability performance of the reported PeLEDs

Perovskite	Structural form	Device architecture	EL peak (nm)	EQE_{max} (%)	Lifetime	Test conditions	Reference
SFB10:$FAPbI_3$	3D	ITO/ZnO/PEIE/perovskite/TFB/MoO_x /Au	803	22.8	T_{50} = 11,539 h T_{50} = 32,575 h	At 5.0 mA cm^{-2} At 3.2mA cm^{-2}	Guo et al., 2022

					No degradation over 3,600 h	At 5.0 mA cm^{-2}	
PAC:(FA/Cs)PbI_3	3D	ITO/ZnO/PEIE/perovskite/TFB/ MoO_3/Au	802	18.6	T_{50} = 682 h	At 20 mA cm^{-2}	Kuang et al.,2021
MSPE:$FAPbI_3$	3D	ITO/ZnO/PEIE/perovskite/poly-TPD/ MoO_x/Au	800	23.8	T_{50} = 32 h	At 100 mA cm^{-2}	Sun et al., 2023
(Cs/Rb/FA)PbI_3	3D	ITO/ZnO/PEIE/perovskite/TFB/ MoO_3/Au	798	15.8	T_{50} = 60 h	At 10 mA cm^{-2}	Li et al., 2020
PEAI:(FA/Cs)Pb$(I/SCN)_3$	3D	ITO/ZnO/PEIE/perovskite/TFB/Au	789	17.5	T_{50} = 130 h	At 100 mA cm^{-2}	Guo Y et al., 2021
AAs:(FA/Cs)Pb$(I/SCN)_3$	3D	ITO/ZnO/PEIE/perovskite/TFB/ MoO_3/Au	785	23.2	T_{50} = 227 h	At 100 mA cm^{-2}	Li Z et al., 2024
SFA: $FA_{0.5}Cs_{0.5}PbI_2Br$	3D	ITO/PEIE/ZnO/perovskite/TFB/MoO_x/Au	710	15.4	T_{50} = 357 h T_{50} = 60.5 h T_{50} = 21.8 h T_{50} = 9.7 h T_{50} = 6.3 h	At 25 mA cm^{-2} At 50 mA cm^{-2} At 100 mA cm^{-2} At 200 mA cm^{-2} At 400 mA cm^{-2}	Ren et al., 2024
GuaI:$CsPbI_3$	3D	ITO/SnO_2/a-ZnO/perovskite/TFB/MoO_x/Au	703	18.8	T_{50} = 33.6 h	At 100 mA cm^{-2}	Zeng et al., 2024
PMA-β-$CsPbI_3$	Nanocrystals	ITO/PEDOT:PSS/poly-TPD/perovskite/TPBi/LiF/Al	689	17.8	T_{50} = 317 h	At 30 mA cm^{-2}	Li et al., 2021
$CsPb(Br_{0.625}/I_{0.375})_3$	3D	ITO/PEDOT:PSS/TFB/LiF/perovskite/TPBi/LiF/Al	656	32.1	T_{50} = 60 h	At 5 mA cm^{-2}	Feng et al., 2024
MM-MOPA:$CsPbI_3$	quasi-2D	ITO/PEDOT:PSS/PTAA/PVP/perovskite/ TPBi/ LiF/Al	638	28.7	T_{50} = 126.8 h	At 0.5 mA cm^{-2}	Kong et al., 2024
DPPA:CsPb(Br/I)$_3$	Nanocrystals	ITO/PEDOT:PSS:PFI/PTAA/perovskite/ TPBi/LiF/Al	638	24.8	T_{50} = 20 h	L_0 = 100 cd m^{-2}	Li H et al., 2024
$CsPbI_3$	Quantum dots	ITO/PEDOT:PSS:PFI/PFN-Br/perovskite/TPBi/LiF/Al	630	24.6	T_{50} = 105.5 h	L_0 = 100 cd m^{-2}	Wei et al., 2025
$MA_{0.8}FA_{0.2}PbBr_3$	3D	ITO/PVK/perovskite/TPBi/LiF/Al	544	11.2	T_{50} = 12,500 h	L_0 = 100 cd m^{-2}	Chen et al., 2023
BPA:$(FA_{0.7}MA_{0.1}GA_{0.2})_{0.87}Cs_{0.13}PbBr_3$	3D	FTO/GraHIL/perovskite/ZADN/LiF/Al	540	28.9	T_{50} = 31,808 h	L_0 = 100 cd m^{-2}	Kim et al., 2022
PEABr:$FAPbBr_3$	Quasi-2D	FTO/NiO_x/PVP/perovskite/TmPPPyTz/LiF/Al	531	29.5	T_{50} = 50,317 h	L_0 = 100 cd m^{-2}	Ding et al., 2024
FPEABr:$CsPbBr_3$	Quasi-2D	ITO/PEDOT:PSS/PFNBr/perovskite/TmPyPB/LiF/Al	526	20.36	T_{50} = 0.11 h	L_0 = 10000 cd m^{-2}	Jiang et al., 2021
$PEA_2Cs_{1.6}MA_{0.4}Pb_3Br_{10}$	Quasi-2D	ITO/PEDOT:PSS/PFI/perovskite/3TPYMB/LiF/Al	517	25.6	T_{50} = 115 h	At 8 mA cm^{-2} L_0 = 7200 cd m^{-2}	Ma et al., 2021

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Crown:MPEG-MAA:$PEA_{0.4}Cs_{0.6}PbBr_3$	Quasi-2D	ITO/poly-TPD/LiF/perovskite/TPBi/CsF/Al	514	28.1	T_{50} = 4.04 h	L_0 = 100 cd m^{-2}	Liu Z et al., 2021
PPNCl:p-F-PEABr:$(Cs/FA/Li)PbBr_xCl_{3-x}$	Quasi-2D	ITO/PVP:PVK/ perovskite/TPBi/Liq/Al	474	13.2	T_{50} = 1.12 h	L_0 = 100 cd m^{-2}	Yuan et al., 2024
$CsPbBr_3$	Quantum dots	ITO/PEDOT:PSS/PVK/perovskite/D-ZnO/Ag	470	8.7	T_{50} = 35 h	L_0 = 100 cd m^{-2}	Liu et al., 2022
$CsPbBr_3$	Quantum dots	ITO/PEDOT:PSS/PVK/perovskite/ZnO/Ag	469	5	T_{50} = 59.2 h	At 7.5 mA cm^{-2}	Yao et al., 2022
$CsPbBr_3$	Quantum dots	ITO/PEDOT:PSS/PVK/perovskite/ZnO/Ag	469	10.3	T_{50} = 25 h	At 12.5 mA cm^{-2}	Bi et al., 2023
FPEA:TFA:$(Cs/PBA/EA/Rb)PbBr_xCl_{3-x}$	Quasi-2D	ITO/SC-PEDOT/perovskite/TPBi/LiF/Al	459	15.36	T_{50} = 2.40 h	At 0.45 mA cm^{-2}	Dong et al., 2025
PBA:EA:$CsPbBr_xCl_{3-x}$	Quasi-2D	ITO/PEDOT:PSS/perovskite/TPBi/LiF/Al	457	4.62	T_{50} = 1.50 h	L_0 = 17.2 cd m^{-2}	Dong et al., 2022

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Author contributions

Z.G. drafted the outline of the review paper under the guidance of D.D. Z.G. and S.Z. wrote the initial draft of the manuscript, which was revised by D.D., B.Z., and W.X.

Conflict of interest

The authors declare no conflict of interest.

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